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Kind regards,

Team Nexperia



# BAT54T

## Single Schottky barrier diode

Rev. 01 — 14 December 2009

Product data sheet

## 1. Product profile

### 1.1 General description

Single planar Schottky barrier diode with an integrated guard ring for stress protection, encapsulated in a SOT416 (SC-75) ultra small Surface-Mounted Device (SMD) plastic package.

### 1.2 Features

- Low forward voltage: max. 400 mV
- Low capacitance: max. 10 pF
- Ultra small SMD plastic package
- AEC-Q101 qualified

### 1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Protection circuits
- Blocking diode

### 1.4 Quick reference data

Table 1. Quick reference data

| Symbol         | Parameter       | Conditions            | Min          | Тур | Max | Unit |
|----------------|-----------------|-----------------------|--------------|-----|-----|------|
| I <sub>F</sub> | forward current |                       | -            | -   | 200 | mA   |
| $V_R$          | reverse voltage |                       | -            | -   | 30  | V    |
| V <sub>F</sub> | forward voltage | $I_F = 10 \text{ mA}$ | <u>[1]</u> _ | -   | 400 | mV   |

[1] Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 



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### Single Schottky barrier diode

## 2. Pinning information

Table 2. Pinning

| Pin      | Description   | Simplified outline | Graphic symbol          |
|----------|---------------|--------------------|-------------------------|
| 4        | •             |                    | оп и <b>р</b> о о уо .  |
| <u> </u> | anode         | □3                 | 3                       |
| 2        | not connected |                    | <u>_</u>                |
| 3        | cathode       | 1 2                | 12<br>n.c.<br>006aaa436 |

## 3. Ordering information

Table 3. Ordering information

| Type number | Package |  |         |
|-------------|---------|--|---------|
|             | Name    | Description                              | Version |
| BAT54T      | SC-75   | plastic surface-mounted package; 3 leads | SOT416  |

## 4. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| BAT54T      | ZW           |

## 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter                              | Conditions                               | Min          | Max  | Unit |
|------------------|--|--|--------------|------|------|
| $V_R$            | reverse voltage                        |  | -            | 30   | V    |
| I <sub>F</sub>   | forward current                        |  | -            | 200  | mA   |
| I <sub>FRM</sub> | repetitive peak forward current        | $t_p \leq 1 \text{ s; } \delta \leq 0.5$ | -            | 300  | mA   |
| I <sub>FSM</sub> | non-repetitive peak<br>forward current | square wave                              |              |      |      |
|                  |  | $t_p = 100 \ \mu s$                      | -            | 4    | Α    |
|                  |  | $t_p = 1 \text{ ms}$                     | -            | 2    | Α    |
|                  |  | t <sub>p</sub> = 10 ms                   | -            | 1    | Α    |
| P <sub>tot</sub> | total power dissipation                | $T_{amb} \le 25  ^{\circ}C$              | <u>[1]</u> _ | 150  | mW   |
| Tj               | junction temperature                   |  | -            | 150  | °C   |
| T <sub>amb</sub> | ambient temperature                    |  | <b>–55</b>   | +150 | °C   |
| T <sub>stg</sub> | storage temperature                    |  | -65          | +150 | °C   |
|                  |  |  |              |      |      |

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

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### Single Schottky barrier diode

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### 6. Thermal characteristics

Table 6. Thermal characteristics

| Symbol         | Parameter  | Conditions  | Min   | Тур | Max | Unit |
|----------------|--|-------------|-------|-----|-----|------|
| $R_{th(j-a)}$  | thermal resistance from junction to ambient      | in free air | [1] - | -   | 833 | K/W  |
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point |             | [2] - | -   | 350 | K/W  |

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

### 7. Characteristics

Table 7. Characteristics

T<sub>amb</sub> = 25 °C unless otherwise specified.

| anno            |                       | •                         |       |     |     |      |
|-----------------|-----------------------|---------------------------|-------|-----|-----|------|
| Symbol          | Parameter             | Conditions                | Min   | Тур | Max | Unit |
| $V_{F}$         | forward voltage       |                           | [1]   |     |     |      |
|                 |                       | $I_F = 0.1 \text{ mA}$    | -     | -   | 240 | mV   |
|                 |                       | I <sub>F</sub> = 1 mA     | -     | -   | 320 | mV   |
|                 |                       | I <sub>F</sub> = 10 mA    | -     | -   | 400 | mV   |
|                 |                       | I <sub>F</sub> = 30 mA    | -     | -   | 500 | mV   |
|                 |                       | I <sub>F</sub> = 100 mA   | -     | -   | 800 | mV   |
| I <sub>R</sub>  | reverse current       | V <sub>R</sub> = 25 V     | -     | -   | 2   | μΑ   |
| t <sub>rr</sub> | reverse recovery time |                           | [2] _ | -   | 5   | ns   |
| $C_d$           | diode capacitance     | $V_R = 1 V$ ; $f = 1 MHz$ | -     | -   | 10  | pF   |

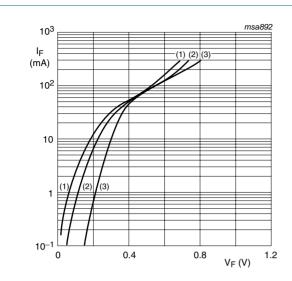
<sup>[1]</sup> Pulse test:  $t_p \le 300 \ \mu s; \ \delta \le 0.02.$ 

<sup>[2]</sup> Soldering point of cathode tab.

<sup>[2]</sup> When switched from  $I_F$  = 10 mA to  $I_R$  = 10 mA;  $R_L$  = 100  $\Omega$ ; measured at  $I_R$  = 1 mA.

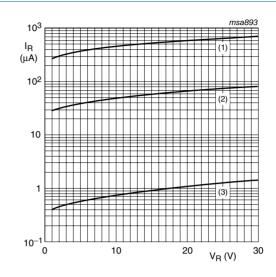
**BAT54T NXP Semiconductors** 

### Single Schottky barrier diode



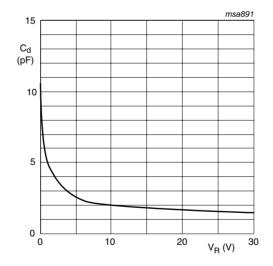
- (1)  $T_{amb} = 125 \, ^{\circ}C$
- (2)  $T_{amb} = 85 \, ^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values



- (1)  $T_{amb} = 125 \, ^{\circ}C$
- (2)  $T_{amb} = 85 \, ^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$

Fig 2. Reverse current as a function of reverse voltage; typical values



f = 1 MHz;  $T_{amb} = 25 \, ^{\circ}\text{C}$ 

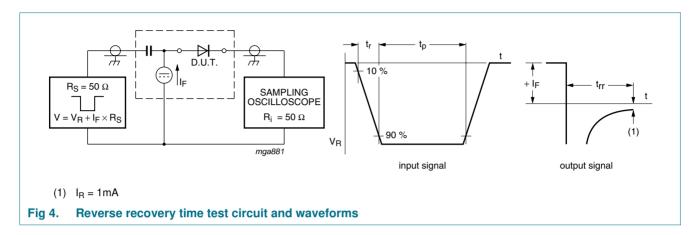
Fig 3. Diode capacitance as a function of reverse voltage; typical values

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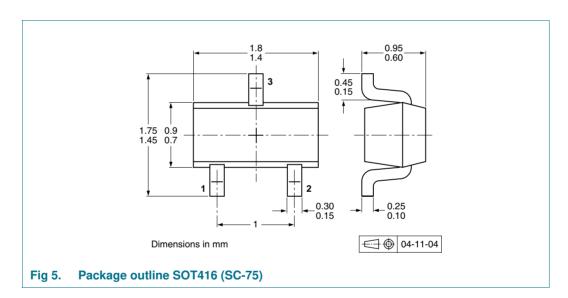
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## 8. Test information



## 9. Package outline



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## 10. Packing information

Table 8. **Packing methods** 

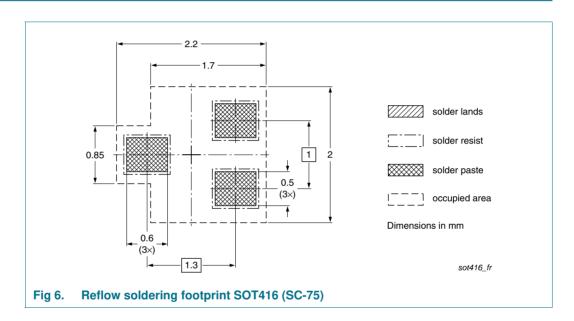
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number | Package | Description                    | Packing quantity |       |
|-------------|---------|--------------------------------|------------------|-------|
|             |         |                                | 3000             | 10000 |
| BAT54T      | SOT416  | 4 mm pitch, 8 mm tape and reel | -115             | -135  |

<sup>[1]</sup> For further information and the availability of packing methods, see Section 14.

## 11. Soldering

**Product data sheet** 



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### Single Schottky barrier diode

## 12. Revision history

### Table 9. Revision history

| Document ID | Release date | Data sheet status  | Change notice | Supersedes |
|-------------|--------------|--------------------|---------------|------------|
| BAT54T_1    | 20091214     | Product data sheet | -             | -          |

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### Single Schottky barrier diode

## 13. Legal information

### 13.1 Data sheet status

| Document status[1][2]          | Product status[3] | Definition  |
|--------------------------------|-------------------|---|
| Objective [short] data sheet   | Development       | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification     | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production        | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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